ASSP 1 Channel 8-bit A/D Converter

MB40528

DESCRIPTION

The MB40528 is a full parallel comparison (flash) type 8-bit resolution analog-to-digital converter, designed for various video and image processing applications.

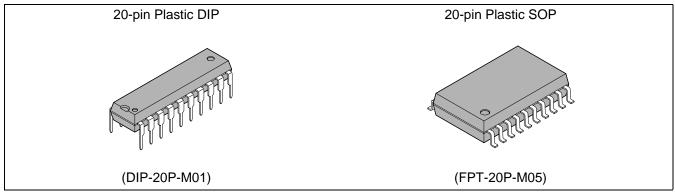
The MB40528 has 8-bit resolution 1 channel A/D converter. Input analog data are converted into digital data by the A/D converter in minimum 60 Mega samples per seconds (MSPS).

The analog data is provided in a range of DC +3V to +5V (2Vp-p level) and the output digital data in TTL level. The MB40528 is fabricated by the Fujitsu's advanced bipolar process and housed in a 20-pin plastic DIP/SOP. The MB40528 is suitable for various video and image applications.

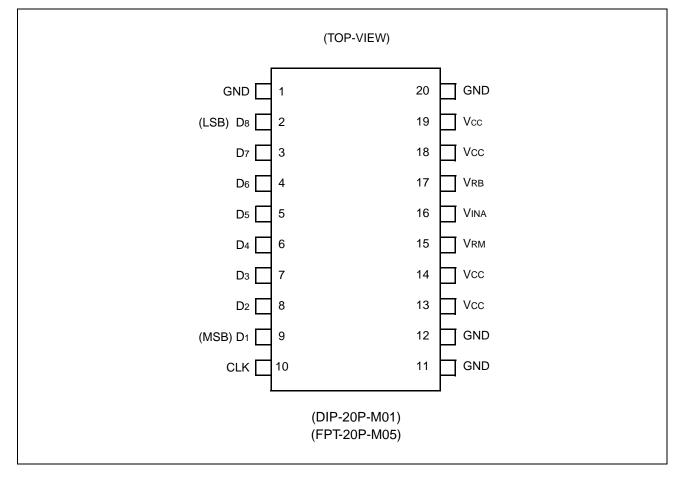
FEATURES

- Conversion method : Full parallel comparison type
- 8-bit x 1 channel A/D converter
- Max. 60 MHz input clock frequency providing 60 MSPS data conversion rate
- Linearity error : Typical +/-0.15%
- Analog input voltage range : 3V to 5V (2Vp-p level)
- Digital input/output voltage level : TTL level
- On-chip reference voltage generator
- Low power consumption : Typical 400mW
- Single +5V power supply
- Operating temperature range : -20°C to +70°C
- Fujitsu's advanced bipolar process

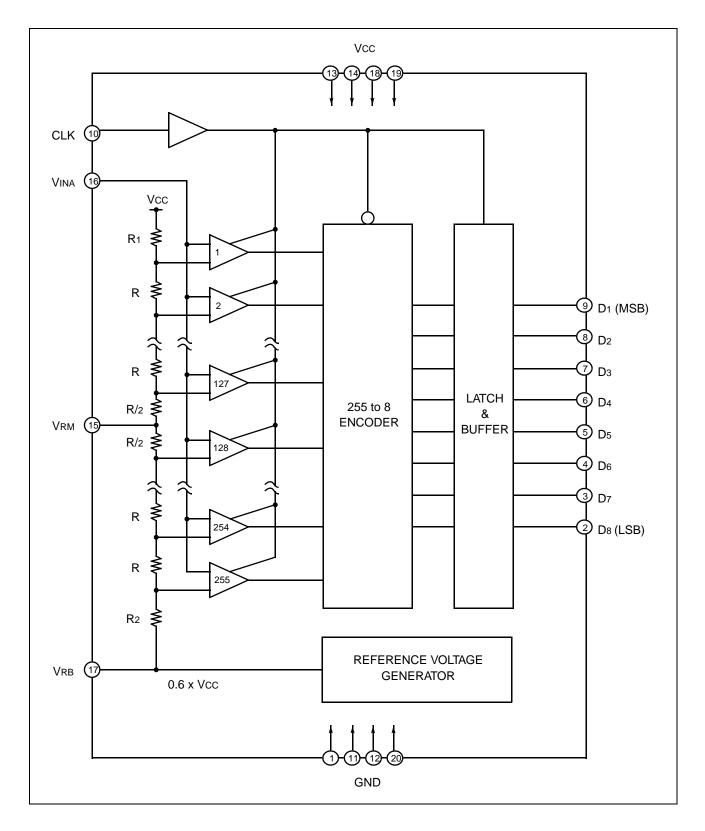
PACKAGES



■ PIN ASSIMENT



■ BLOCK DIAGRAM



■ PIN DESCRIPTION

Symbol	Pin No.	Туре	Name & Function			
Power Supp	ly					
Vcc	13, 14, 18, 19	-	+5 V DC power supply pins.			
GND	1, 11, 12, 20	-	Ground pins.			
Clock						
CLK	10	I	Clock input pin. The input voltage is a TTL level.			
Analog Inpu	t		·			
Vina	16	Ι	Analog signal input pin. The analog data to be converted is input to this pin. The input voltage range is 3V to 5V (VRB to VCC).			
Digidal Outp	but		·			
D1	9					
D2	8					
D3	7					
D4	6	0	8-bit resolution A/D converter outputs. The output voltage is a TTL level.			
D5	5	0	Also, D1 pin is an MSB and D8 pin is a LSB.			
D6 4 D7 3						
D8	2					
Refernce Vo	Itage Output					
Vrb	17	0	Reference voltage output pin. This pin outputs 0.6 x Vcc [V] (T $3V$). An 1μ F or more capacitor having superior frequency characteristic should be connected to this pin. The capacitor m be connected near the device.			
Others						
Vrm	15	0	An intermediate voltage output pin. An intermediate voltage between Vcc and VRB (Typ. 4V) is output from this pin. Normally this pin is left open.			

ABSOLUTE MAXIMUM RATINGS

					(GND = 0 V)
Parameter	Symbol	Condition	Ra	Unit	
Falameter	Symbol	Condition	Min.	Max.	
Supply Voltage	Vcc	-	-0.5	+7.0	V
Analog Input Voltage	Vina	-	-0.5	Vcc +0.5	V
Digital Input Voltage	Vind	-	-0.5	+7.0	V
Storage Temperature	Tstg	-	-55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

RECOMMENDED OPERATING CONDITIONS

					(0	GND = 0 V)
Parameter	Symbol	Condition	Value			Unit
Farameter			Min.	Тур.	Max.	Unit
Supply Voltage	Vcc	-	4.75	5.00	5.25	V
Analog Input Voltage	Vina	-	Vrb	-	Vcc	V
Digital "H" Level Input Voltage	Vihd	-	2.0	-	-	V
Digital "L" Level Input Voltage	Vild	-	-	-	0.8	V
Digital "H" Level Output Current	Юн	-	-400	-	-	μΑ
Digital "L" Level Output Current	IOL	-	-	-	1.6	mA
Clock Frequency	fCLK	-	-	-	60	MHz
Minimum Clock "H" Level Pulse Width	twH	-	7.0	-	-	ns
Minimum Clock "L" Level Pulse Width	twL	-	8.0	-	-	ns
Operating Ambient Temperature	Ta	-	-20	-	70	°C

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating conditionranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC CHARACTERISTICS

(1) Analog Block

Parameter	Symbol	Condition	Value			Unit	
Falameter	Symbol	Condition	Min.	Тур.	Max.	Unit	
Resolution	-	_	-	8	—	bit	
Linearity Error	LE	DC Accuracy	-	±0.15	±0.3	%	
Differentioal Linearity Error	DLE	DC Accuracy	-	0.12	-	%	
Analog Input Equivalent Resister	Rina	-	0.2	1.5	-	MΩ	
Analog Input Capacitance	CINA	_	-	40	-	pF	
Analog "H" Level Input Current	Ііна	VINA = VCC	-	-	210	μΑ	
Analog "L" Level Input Current	IILA	VINA = VREF	-	-	200	μΑ	
Reference Voltage	Vrb	-	0.6Vcc-0.1	0.6Vcc	0.6Vcc+0.1	V	
Supply Current	lcc	_	_	80*	150	mA	

* : Vcc = 5.0V, Ta = +25°C

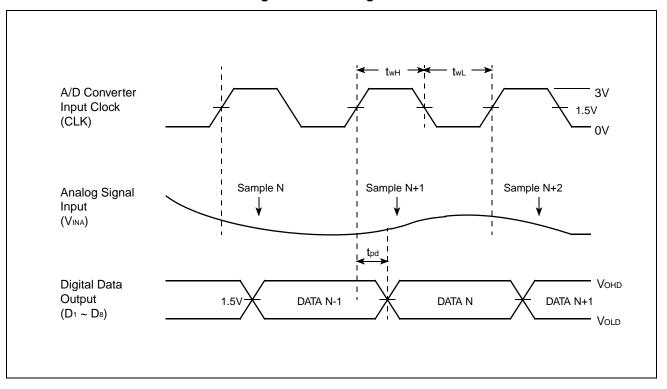
(2) Digital Block

Parameter	Symbol	Condition	Value			Unit
Falameter	Symbol	Condition	Min.	Тур.	Max.	Onit
Digital "H" Level Output Voltage	Vohd	Іон =-400μА	2.7	-	—	V
Digital "L" Level Output Voltage	Vold	IOL = 1.6mA	-	-	0.4	V
Digital "H" Level Input Voltage	Vihd	_	2.0	-	_	V
Digital "L" Level Input Voltage	VILD	_	-	-	0.8	V
Digital "H" Level Input Current	Iihd	_	-	_	20	μΑ
Digital "L" Level Input Current	lild	_	-100	_	_	μΑ

2. AC CHARACTERISTICS

Parameter	Symbol	Condition	Condition			Unit	
Falameter	Symbol	Condition	Min. Typ. Max.			Unit	
Maximum Conversion Rate	fs	_	60	-	_	MSPS	
Digital Output Delay Time	tpd	_	5.0	8.5	15	ns	

Figure 1. AC Timing Chart



■ EQUIVALENT CIRCUITS

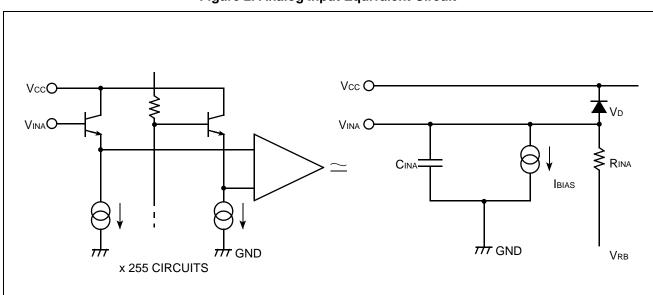


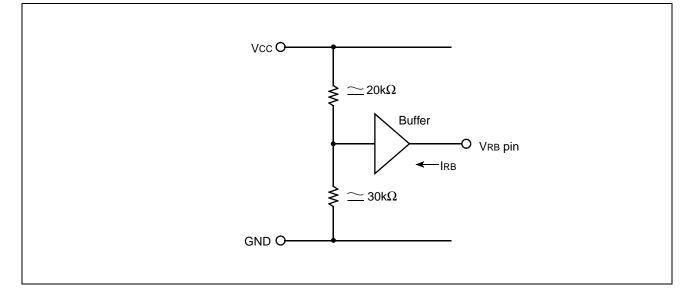
Figure 2. Analog Input Equivalent Circuit

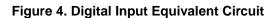
CINA: Non-linear Emitter-follower Junction Capacitance

RINA: Linear Resistance Model for Input Current Transition by Comparator Switching: finite value for VINA < VRB or when CLK = "H" level

- $\label{eq:VRB:VRB} \mbox{VRB pin (Not the VRB pin itself)}$
- IBIAS: Constant Input Bias Current
- VD: The base-collector junction diode of emitter-follower transistor.

Figure 3. Reference Voltage Circuit





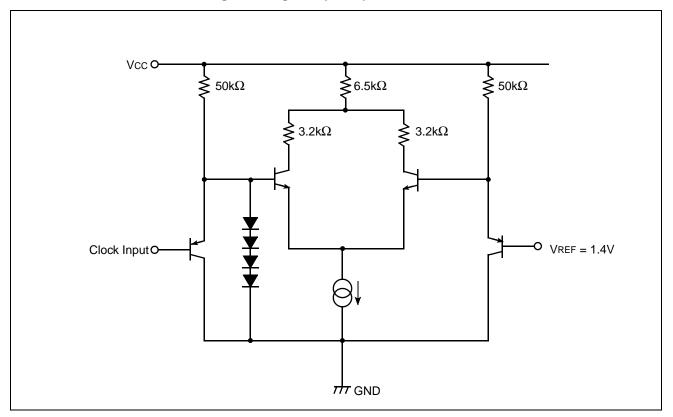
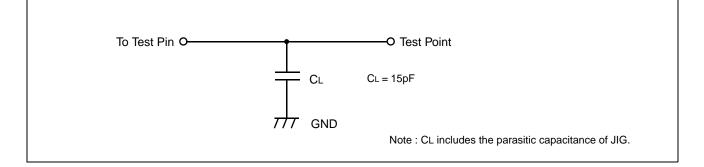
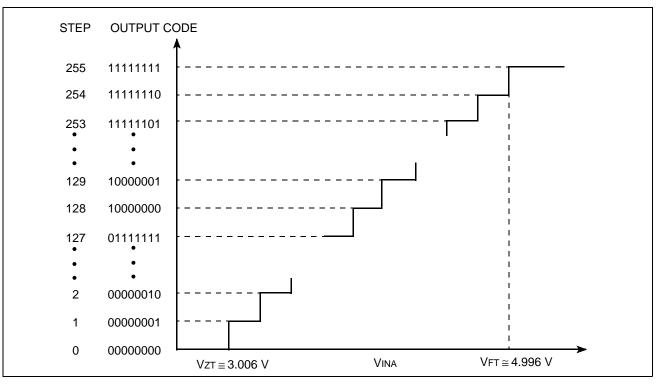


Figure 5. Output Buffer Load Circuit



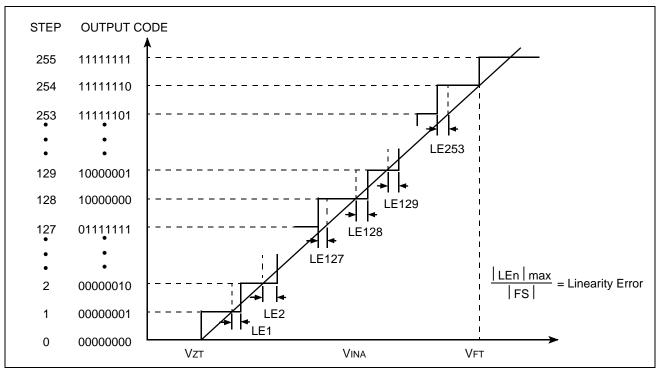
■ LINEARITY ERROR

1. Ideal Conversion Characteristic



VZT and VFT are the typical values when Vcc = 5 V and VRB = 3 V.

2. Actual Conversion Characteristic



NOTE: Refer to "ELECTRICAL CHARACTERISTICS" for a range of VINA inputs.

NOTES ON USE

1. Power Supply Patterns of the PCB

The power supply wire patterns (Vcc and GND patterns) of the PCB should be designed as wide as possible in order to reduce parasitic impedance.

Also, the Vcc and GND patterns which are connected to the Vcc and GND pins of the device must be handled and designed as analog system pattern and so, their circuit patterns must be separate from digital system patterns of other peripheral devices.

2. Switching Noise

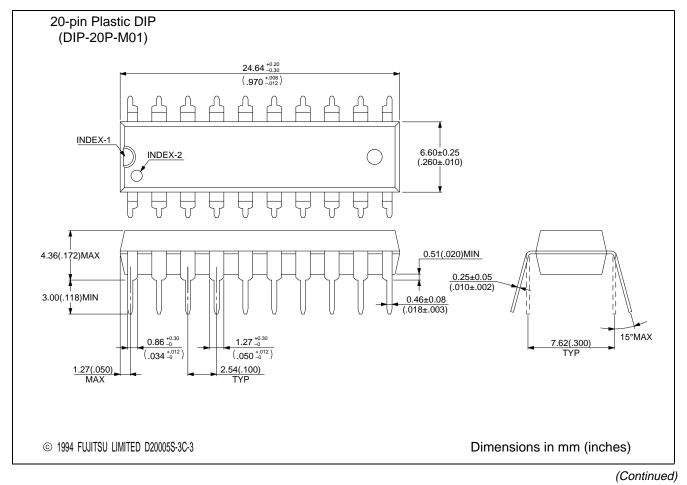
In order to reduce switching noise as much as possible, high-frequency bypass capacitor must be connected between V_{CC} and GND pins and V_{RB} and GND pins.

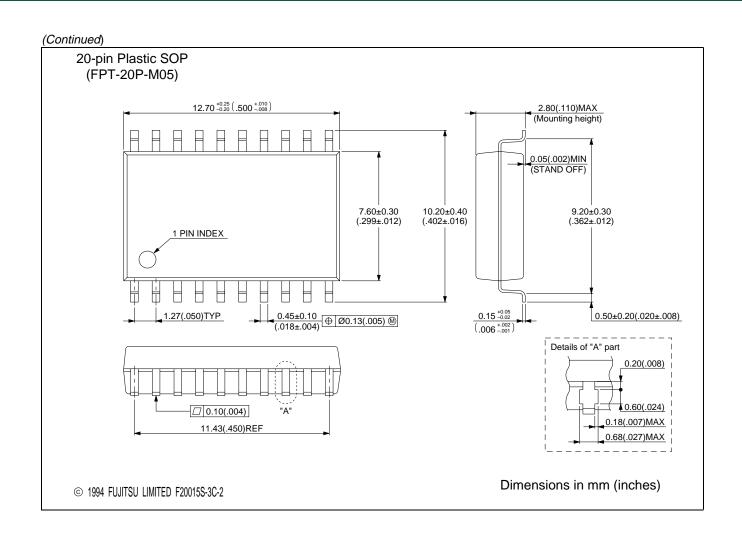
In this case, the capacitor should be connected to the pins as near as possible.

ORDERING INFORMATION

Part number	Package	Remarks
MB40528P	20-pin Plastic DIP (DIP-20P-M01)	
MB40528PF	20-pin Plastic SOP (FPT-20P-M05)	

■ PACKAGE DIMENSIONS





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